

20V PNP LOW SATURATION SWITCHING TRANSISTOR IN SOT26
Features

- $BV_{CEO} > -20V$
- $I_C = -2.5A$ Continuous Collector Current
- $I_{CM} = -6A$ Peak Pulse Current
- $R_{CE(sat)} = 96m\Omega$ for a Low Equivalent On-Resistance
- Low Saturation Voltage (-220mV max @ 1A)
- h_{FE} Characterized up to -6A for High Current Gain Hold-Up
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

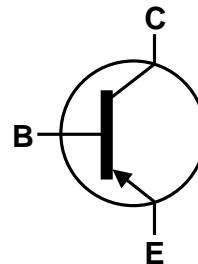
- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.015 grams (Approximate)

Applications

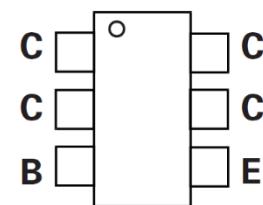
- DC-DC Converters
- Power Management Functions
- Power Switches
- Motor Control



Top View



Device Symbol



Pin-Out Top

Ordering Information (Note 4)

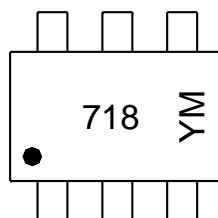
Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXT10P20DE6TA	718	7	8	3,000
ZXT10P20DE6TC	718	13	8	10,000

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information

SOT26



718 = Product Type Marking Code

YM = Date Code Marking

 Y or \bar{Y} = Year (ex: C = 2015)

 M or \bar{M} = Month (ex: 9 = September)

Date Code Key

Year	2015	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025
Code	C	D	E	F	G	H	I	J	K	L	M

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-20	V
Collector-Emitter Voltage	V_{CEO}	-20	V
Emitter-Base Voltage	V_{EBO}	-7	V
Base Current	I_B	-500	mA
Continuous Collector Current	I_C	-2.5	A
Peak Pulse Collector Current	I_{CM}	-6	A

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor	P_D	1.1	W mW/°C
		8.8	
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	1.7	°C/W
		13.6	
Thermal Resistance, Junction to Leads	$R_{\theta JL}$	113	
Operating and Storage Temperature Range	T_J, T_{STG}	73	°C/W
		30.01	
		-55 to +150	°C

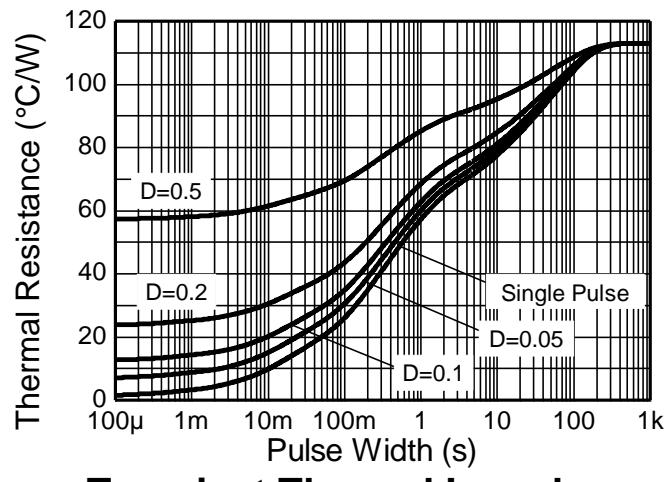
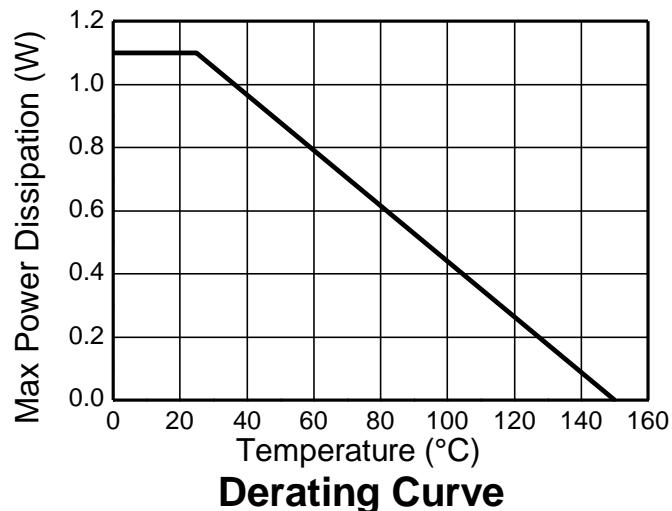
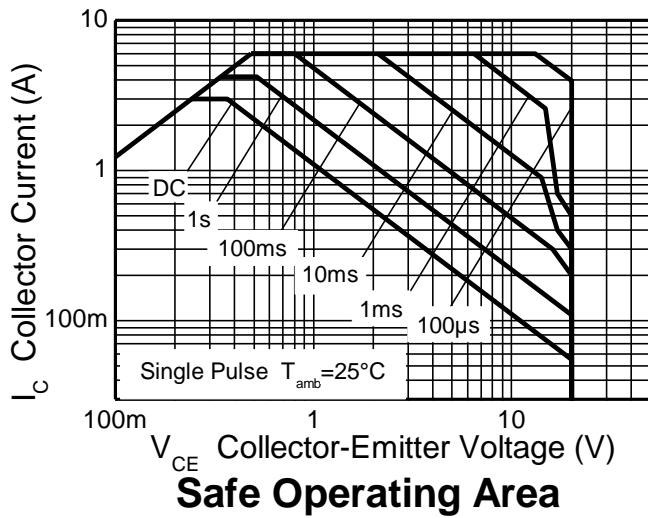
ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:

- 5. For a device mounted with collector leads on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is measured at $t \leq 5\text{secs}$.
- 7. Thermal resistance from junction to solder-point (at the end of the collector leads).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information

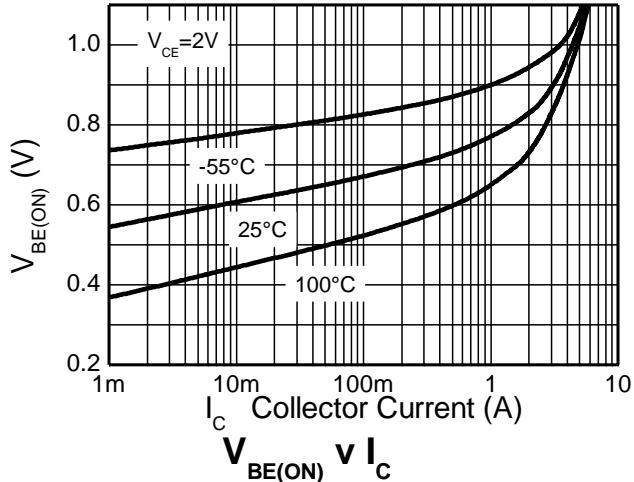
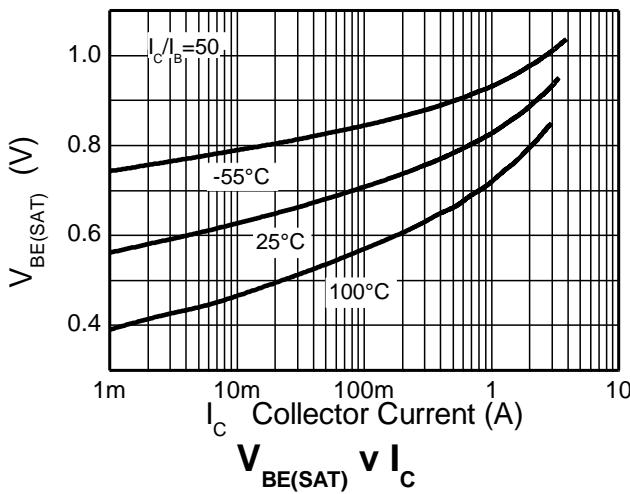
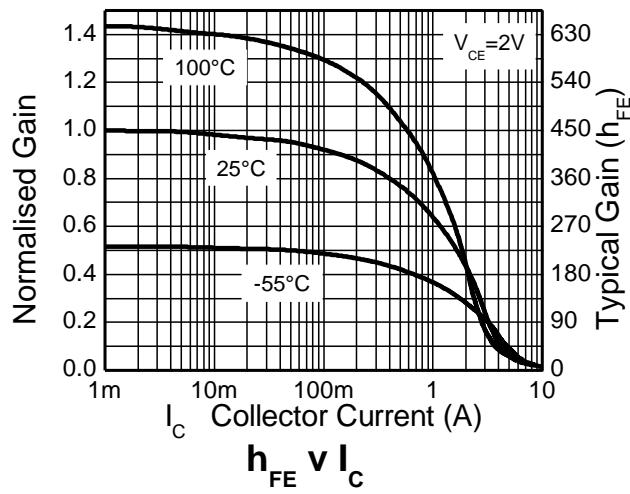
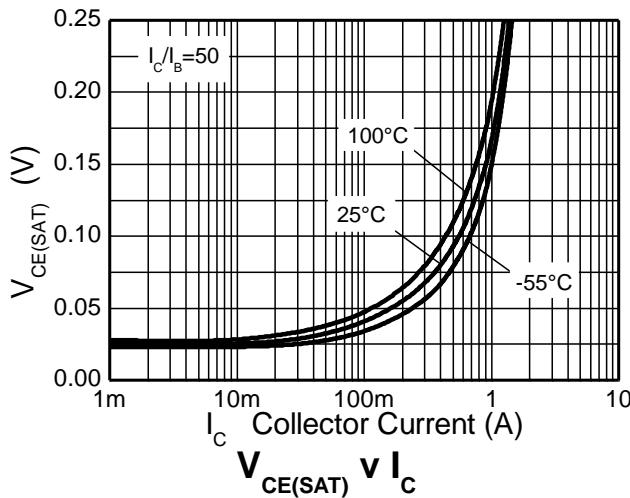
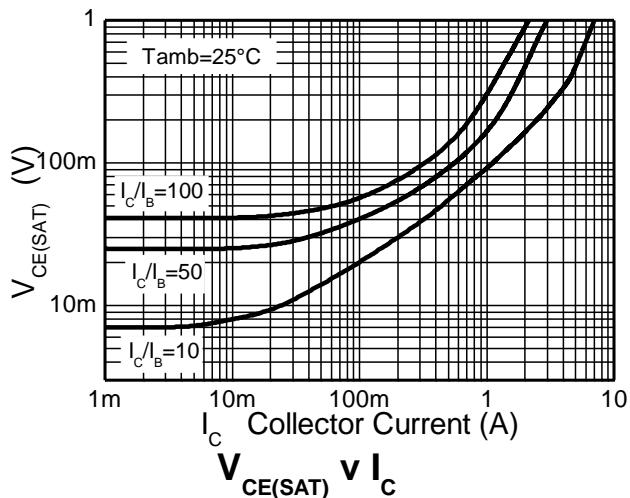


Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV_{CBO}	-20	-65	—	V	$I_C = -100\mu\text{A}$
Collector-Emitter Breakdown Voltage (Note 9)	BV_{CEO}	-20	-53	—	V	$I_C = -10\text{mA}$
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	-8.8	—	V	$I_E = -100\mu\text{A}$
Collector-Base Cutoff Current	I_{CBO}	—	<1	-100	nA	$V_{\text{CB}} = -15\text{V}$
Emitter Cutoff Current	I_{EBO}	—	<1	-100	nA	$V_{\text{EB}} = -5\text{V}$
Collector-Emitter Cutoff Current	I_{CES}	—	<1	-100	nA	$V_{\text{CES}} = -15\text{V}$
ON CHARACTERISTICS (Note 9)						
DC Current Gain	h_{FE}	300	475	—	—	$I_C = -10\text{mA}, V_{\text{CE}} = -2\text{V}$
		300	450	—	—	$I_C = -0.1\text{A}, V_{\text{CE}} = -2\text{V}$
		150	230	—	—	$I_C = -2\text{A}, V_{\text{CE}} = -2\text{V}$
		15	30	—	—	$I_C = -6\text{A}, V_{\text{CE}} = -2\text{V}$
Collector-Emitter Saturation Voltage	$V_{\text{CE}(\text{sat})}$	—	-19	-30	mV	$I_C = -0.1\text{A}, I_B = -10\text{mA}$
		—	-170	-220		$I_C = -1\text{A}, I_B = -20\text{mA}$
		—	-190	-250		$I_C = -1.5\text{A}, I_B = -50\text{mA}$
		—	-240	-350		$I_C = -2.5\text{A}, I_B = -150\text{mA}$
Base-Emitter Saturation Voltage	$V_{\text{BE}(\text{sat})}$	—	-0.97	-1.05	V	$I_C = -2.5\text{A}, I_B = -150\text{mA}$
Base-Emitter Turn-On Voltage	$V_{\text{BE}(\text{on})}$	—	-0.85	-0.95	V	$I_C = -2.5\text{A}, V_{\text{CE}} = -2\text{V}$
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f_T	150	180	—	MHz	$V_{\text{CE}} = -10\text{V}, I_C = -50\text{mA}, f = 100\text{MHz}$
Output Capacitance	C_{obo}	—	21	30	pF	$V_{\text{CB}} = -10\text{V}, f = 1\text{MHz}$
Turn-On Time	$t_{(\text{on})}$	—	40	—	ns	$V_{\text{CC}} = -10\text{V}, I_C = -1\text{A}$
Turn-Off Time	$t_{(\text{off})}$	—	670	—	ns	$I_{B1} = -I_{B2} = -20\text{mA}$

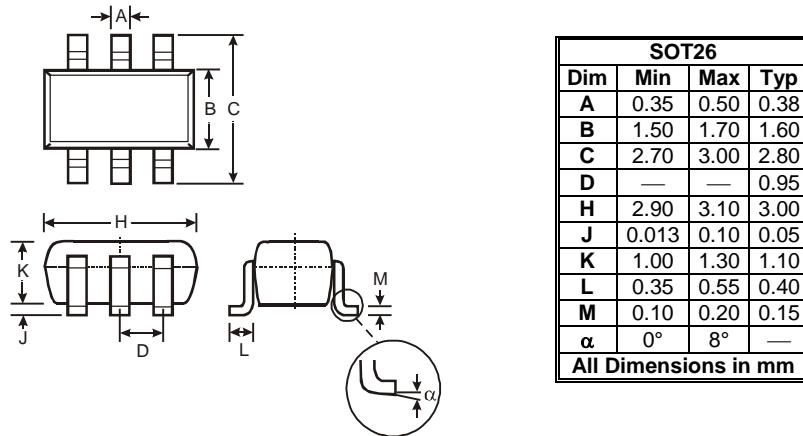
Note: 9. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



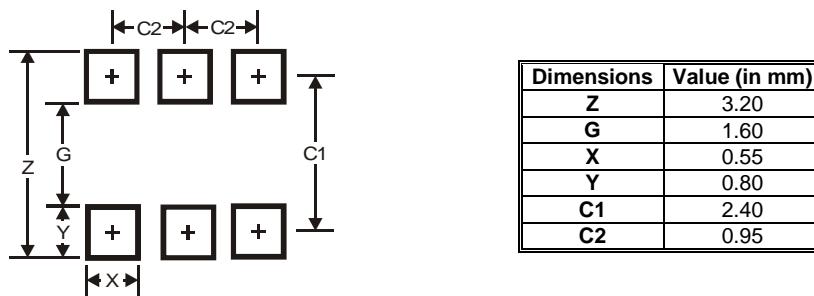
Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



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